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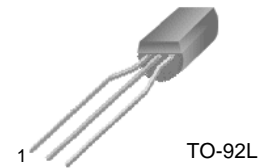
November 2014

# KSC2331

## NPN Epitaxial Silicon Transistor

### Features

- Low-Frequency Amplifier and Medium Speed Switching
- Complement to KSA931
- High Collector-Base Voltage:  $V_{CBO} = 80\text{ V}$
- Collector Current:  $I_C = 700\text{ mA}$



1. Emitter 2. Collector 3. Base

### Ordering Information

Part Number	Top Mark	Package	Packing Method
KSC2331YTA	C2331 Y-	TO-92 3L	Ammo

### Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	80	V
$V_{CEO}$	Collector-Emitter Voltage	60	V
$V_{EBO}$	Emitter-Base Voltage	8	V
$I_C$	Collector Current	700	mA
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-55 to +150	$^\circ\text{C}$

**Thermal Characteristics<sup>(1)</sup>**

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$P_D$	Power Dissipation	1	W
	Derate Above $25^\circ\text{C}$	8.0	mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	125	$^\circ\text{C}/\text{W}$

**Note:**

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

**Electrical Characteristics**

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = 100 \mu\text{A}$ , $I_E = 0$	80			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}$ , $I_B = 0$	60			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu\text{A}$ , $I_C = 0$	8			V
$I_{CBO}$	Collector Cut-Off Current	$V_{CB} = 60 \text{ V}$ , $I_E = 0$			0.1	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-Off Current	$V_{EB} = 5 \text{ V}$ , $I_C = 0$			0.1	$\mu\text{A}$
$h_{FE}$	DC Current Gain	$V_{CE} = 2 \text{ V}$ , $I_C = 50 \text{ mA}$	40		240	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 500 \text{ mA}$ , $I_B = 50 \text{ mA}$		0.2	0.7	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 500 \text{ mA}$ , $I_B = 50 \text{ mA}$		0.86	1.20	V
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10 \text{ V}$ , $I_C = 50 \text{ mA}$	30	50		MHz
$C_{ob}$	Output Capacitance	$V_{CB} = 10 \text{ V}$ , $I_E = 0$ , $f = 1 \text{ MHz}$		8		pF

 **$h_{FE}$  Classification**

Classification	R	O	Y
$h_{FE}$	40 ~ 80	70 ~ 140	120 ~ 240

Typical Performance Characteristics

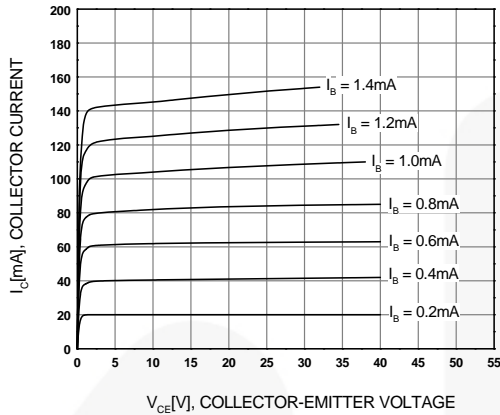


Figure 1. Static Characteristic

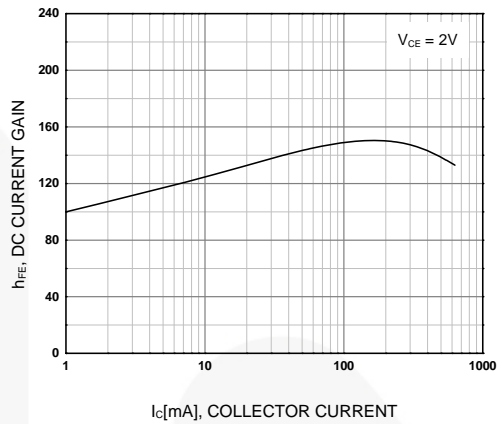


Figure 2. DC Current Gain

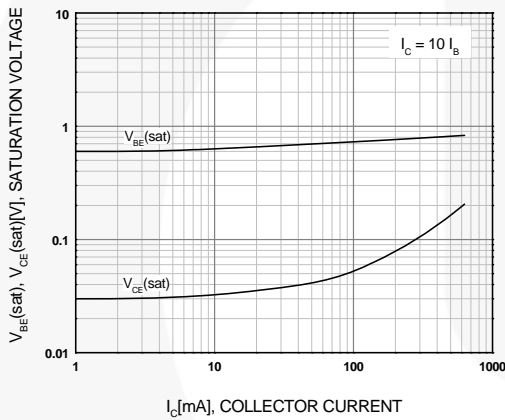


Figure 3. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

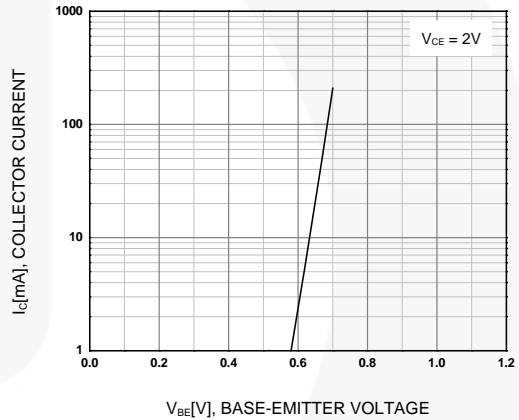


Figure 4. Base-Emitter On Voltage

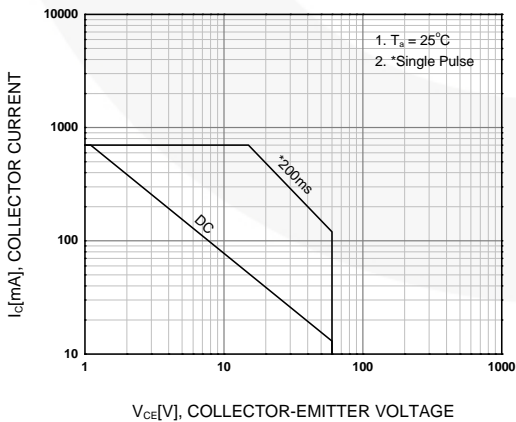


Figure 5. Safe Operating Area

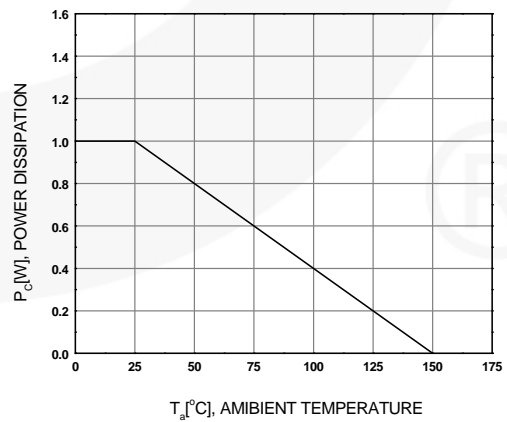
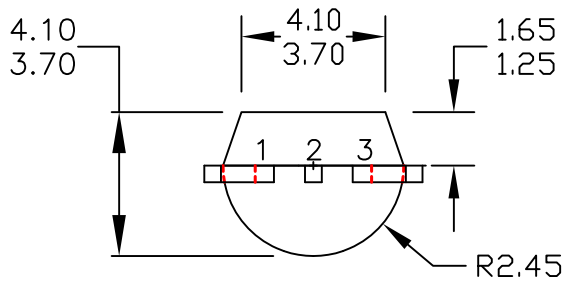
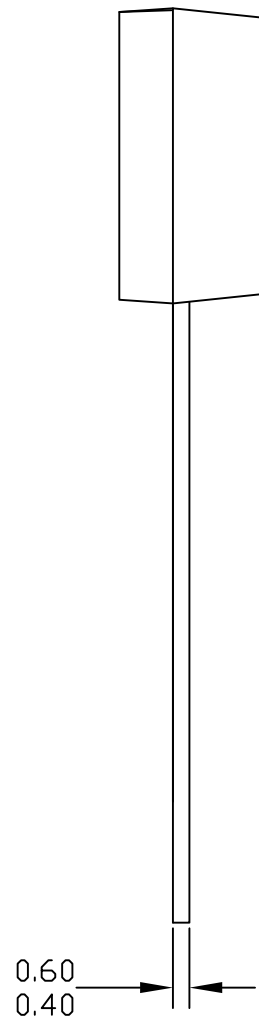
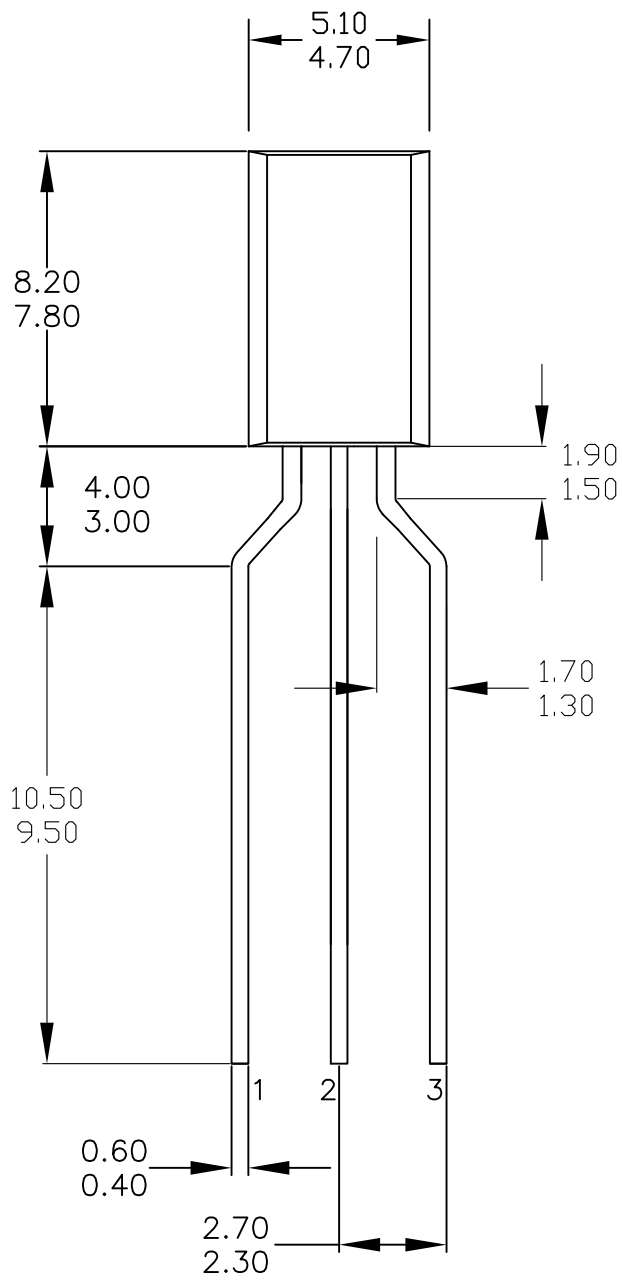


Figure 6. Power Derating



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